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Vishay Siliconix

Automotive N-Channel 200 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY						
V _{DS} (V)	200					
$R_{DS(on)}$ (Ω) at $V_{GS} = 10 \text{ V}$	0.0153					
I _D (A)	95					
Configuration	Single					
Package	TO-263					

FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



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N-Channel MOSFET	o S

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	200	V	
Gate-source voltage		V_{GS}	± 20	V	
Continuous drain current	T _C = 25 °C	- I _D	95		
Continuous drain current	T _C = 125 °C		55		
Continuous source current (diode conduction	Is	120	А		
Pulsed drain current ^b	I _{DM}	170			
Single pulse avalanche current	L = 0.1 mH	I _{AS}	64		
Single pulse avalanche energy	L=0.11IIII	E _{AS}	205	mJ	
Maximum power dissipation ^b	T _C = 25 °C	- P _D	375	W	
iviaximum power dissipation -	T _C = 125 °C		125		
Operating junction and storage temperature r	ange	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-ambient	PCB mount c	R_{thJA}	40	°C/W		
Junction-to-case (drain)		R_{thJC}	0.4	C/VV		

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300 \,\mu\text{s}$, duty cycle $\leq 2 \,\%$.
- c. When mounted on 1" square PCB (FR4 material).



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static					•			
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		200	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	2.5	3.0	3.5	V	
Gate-source leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 200 V	-	-	1		
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 200 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	ı	-	50	μΑ	
		$V_{GS} = 0 V$	V _{DS} = 200 V, T _J = 175 °C	-	-	600		
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	40	-	-	Α	
		V _{GS} = 10 V	I _D = 20 A	ı	0.0127	0.0153		
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}$	I _D = 20 A, T _J = 125 °C	ı	-	0.0310	Ω	
		V _{GS} = 10 V	I _D = 20 A, T _J = 175 °C	1	-	0.0404		
Forward transconductance b	9 _{fs}	V_{DS}	V _{DS} = 15 V, I _D = 20 A		54	-	S	
Dynamic ^b								
Input capacitance	C _{iss}		V _{DS} = 25 V, f = 1 MHz	-	3200	4200	pF	
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	1300	1750		
Reverse transfer capacitance	C _{rss}			-	80	110		
Total gate charge ^c	Q_g			-	55	85	nC	
Gate-source charge ^c	Q_{gs}	$V_{GS} = 10 \text{ V}$	$V_{GS} = 10 \text{ V}$ $V_{DS} = 100 \text{ V}, I_D = 9 \text{ A}$		14	-		
Gate-drain charge ^c	Q_{gd}				16.5	-		
Gate Resistance	R_g	f = 1 MHz		1.35	2.74	4.20	Ω	
Turn-on delay time ^c	t _{d(on)}			-	17	30		
Rise time ^c	t _r		V_{DD} = 100 V, R_L = 11.1 Ω $I_D \cong$ 9 A, V_{GEN} = 10 V, R_g = 1 Ω		8	15	- ns	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 9 A$,			39	60		
Fall time ^c	t _f			-	16	30		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed current ^a	I _{SM}			-	-	170	Α	
Forward voltage	V _{SD}	I _F =	I _F = 20 A, V _{GS} = 0 V		0.82	1.5	V	
Body diode reverse recovery time	t _{rr}	I _F = 10 A, di/dt = 100 A/μs		-	129	260	ns	
Body diode reverse recovery charge	Q _{rr}			-	685	1400	nC	
Reverse recovery fall time	t _a			ı	106	-	ns	
Reverse recovery rise time	t _b			-	26	-		
Body diode peak reverse recovery current	I _{RM(REC)}		-	-11	-	Α		

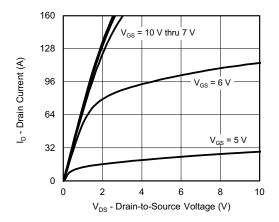
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

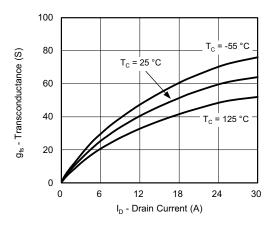
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



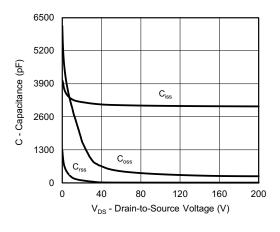
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



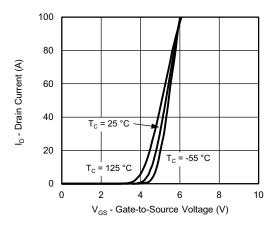
Output Characteristics



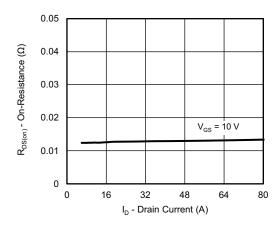
Transconductance



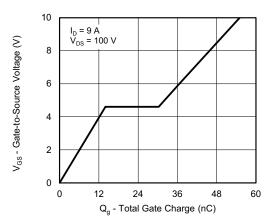
Capacitance



Transfer Characteristics



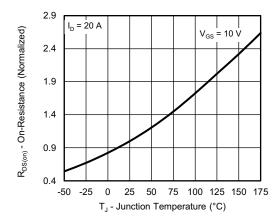
On-Resistance vs. Drain Current



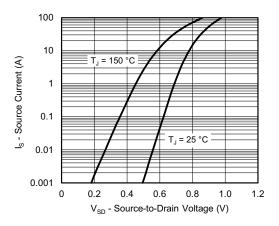
Gate Charge



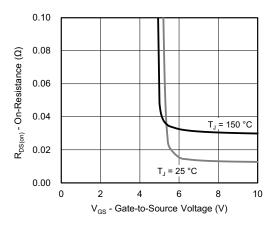
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



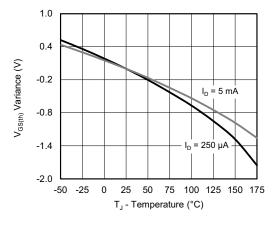
On-Resistance vs. Junction Temperature



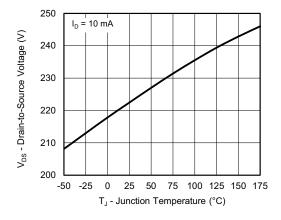
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



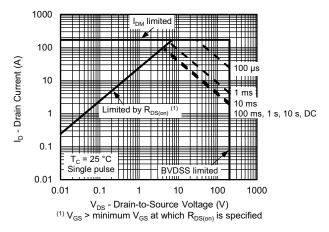
Threshold Voltage



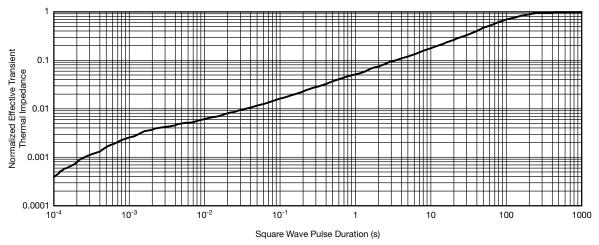
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



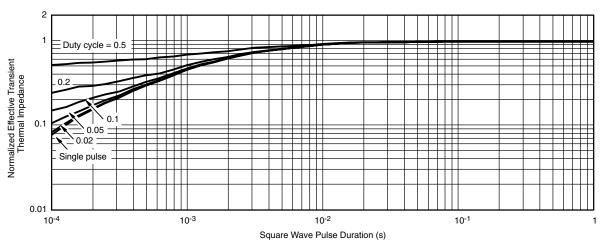
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

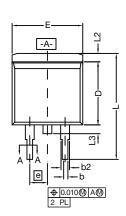
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction to Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single

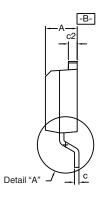
pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

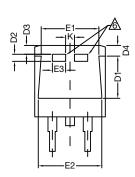
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?77719



TO-263 (D²PAK): 3-LEAD

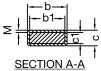








DETAIL A (ROTATED 90°)



_ - b1 , , ,	
≥ 	- -

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6. This feature is for thick lead.

		INC	HES	MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
D2		0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
D4		0.044	0.052	1.118	1.321	
E		0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	=	
	E2	0.355	0.375 9.017 9.52		9.525	
	E3	0.072	0.078	1.829	1.981	
е		0.100) BSC	2.54 BSC		
K		0.045	0.055	1.143	1.397	
	L	0.575	0.625	14.605	15.875	
	L1	0.090	0.110	2.286	2.794	
	L2	0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
	L4	0.010 BSC		0.254 BSC		
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13						

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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